# NSN 5961-01-102-0439

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# **Inclosure Material:**

Metal

**Overall Length:** 

0.340 inches

# **Overall Diameter:**

0.620 inches

# **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-66

Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

# **Features Provided:**

Hermetically sealed case

#### **Semiconductor Material:**

Silicon

#### Voltage Rating In Volts Per Characteristic:

100.0 collector to base voltage/static/emitter open and 80.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 4.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

# **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

# **Terminal Type And Quantity:**

1 case and 2 pin

# **Specification Data:**

81349-mil-s-19500/518 government specification

# Shelf Life:

N/a

# Unit Of Measure:

- **Demilitarization:**

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